ARMSTRO

RMAN, HATTORI, MCLELAND & NAUGHTON

Declaration For U.S. Patent Application

As a below named inventor, I hereby declare that:

My residence, po	ost office address and citizenship are as state	d bolow next to my nan	ne.		
I believe I am the names are listed (Insert Title)	e original, first and sole inventor (if only one below) of the subject matter which is claims Semiconductor Device and Fab	d and for which a nater	it is collect on the invention and it	tor (if plural	
the specification	of which is attached hereto unless the follow	ving is checked:			
				-	
	was filed on	as Uni	ted States Application Number or	PCT International	
	Application Number		and was amended on		
	(if applicable).	,	,		
o, and afferigine	t I have reviewed and understand the content nt referred to above.				
I acknowledge the	e duty to disclose information which is materi	al to patentability as def	fined in Title 37, Code of Federal R	egulations, § 1.56.	
	reign priority benefits under Title 35, United cate listed below and have also identified bel nat of the application on which priority is cla	OW SHY toteldh anniica	- (d) of any foreign application(s) tion for patent or inventor's certific	cate having a fil-	
(List prior	10-149456(P)	Japan	29/May/1998	Priority Claimed Yes D No	
ëforeign ≣applications.	(Number) 10-308754(P)	(Country) Japan	(Day/Month/Year Filed) 29/October/1998	_ 2a Yes □ No	
See note A	(Number)	(Country)	(Day/Month/Year Filed)		
ion back of this page)	(Number)	(Country)	(Day/Month/Year Filed)	_ O Yes O No	
	(Number)	(Country)	(Day/Month/Year Filed)	_ Q Yes Q No	
≡ See note B on ba	ick of this page)	list for additional prior	francisco annolisado a		
ii '					
hereby claim the	benefit under Title 35, United States Code,	§ 119(e) of any United	States provisional application(s) li	isted below.	
U M			<u> </u>	•	
	(Application Number)		(Filing Date)	_	
	(Application Number)		(Filing Date)	_	
he first paragraph ty as defined in T	benefit under Title 35, United States Code, each of the claims of this application is not on of Title 35, United States Code, § 112, I active 37, Code of Federal Regulations, § 1.56 r PCT international filing date of the applications.	isclosed in the prior Ui knowledge the duty to (which became available	nited States application in the many	ner provided by	
(List Prior U.S. Applications)	(Application Serial Number)	(Filing Date)	(Status) (patented, pendin	g, abandoned)	
	(Application Serial Number)	(Filing Date)	(Status) (patented, pendin	g, abandoned)	
hereby appoint d	he following attorney(s) and/or agent(s) to p	racousta this analisasis		· ,	

I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and to transact all business in the Patent and Trad mark Office connected therewith:

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be tru; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Title 18 of the United States Code, § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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